Trench-based Schottky Rectifier

Features

- Fine Lithography Trench-based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- High Surge Capability
- NRV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Switching Power Supplies including Tablet Adapters, and Flat Panel Display
- High Frequency and DC-DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics:

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94–0 @ 0.125 in.
- Lead Finish: 100% Matte Sn (Tin)
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL 1 Requirements
- Weight: 95 mg (Approximately)



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TRENCH SCHOTTKY RECTIFIER 3.0 AMPERE 45 VOLTS



SMA-FL CASE 403AA STYLE 6

MARKING DIAGRAM



3AR = Specific Device Code A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NTSAF345T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel
NRVTSAF345T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	45	V
Average Rectified Forward Current (T _L = 112°C)	lo	3.0	А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _L = 103°C	I _{FRM}	6.0	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	100	А
Storage Temperature Range	T _{stg}	-65 to +150	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2)	$\Psi_{\sf JCL}$	25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	90	°C/W

^{2. 1} inch square pad size (1×0.5) inch) for each lead on FR4 board.

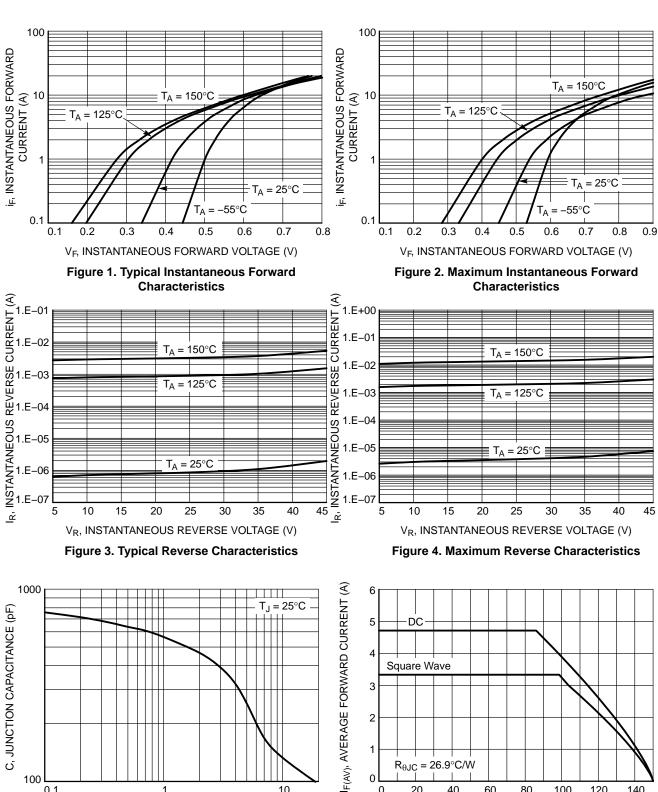
ELECTRICAL CHARACTERISTICS

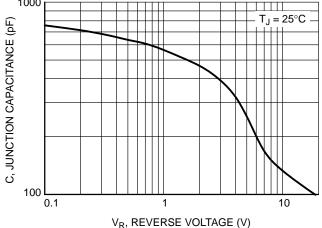
Rating	Symbol	Тур	Max	Unit
Instantaneous Forward Voltage (Note 3) $(I_F = 3 \text{ A}, T_J = 25^{\circ}\text{C})$ $(I_F = 3 \text{ A}, T_J = 125^{\circ}\text{C})$	V _F	0.482 0.4	0.63 0.55	V
Instantaneous Reverse Current (Note 3) (Rated dc Voltage, T _J = 25°C) (Rated dc Voltage, T _J = 125°C)	I _R	1.75 1.45	7.5 3	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: Pulse Width \leq 380 μ s, Duty Cycle \leq 2.0%.

^{1.} The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

TYPICAL CHARACTERISTICS







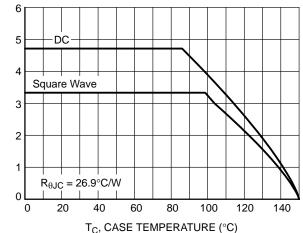
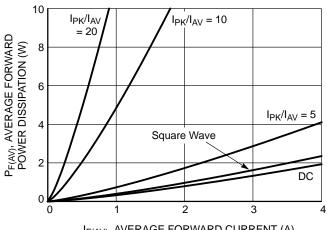


Figure 6. Current Derating per Device

TYPICAL CHARACTERISTICS



I_{F(AV)}, AVERAGE FORWARD CURRENT (A)

Figure 7. Forward Power Dissipation

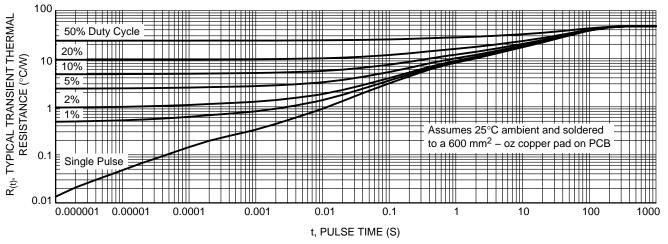


Figure 8. Typical Thermal Characteristics

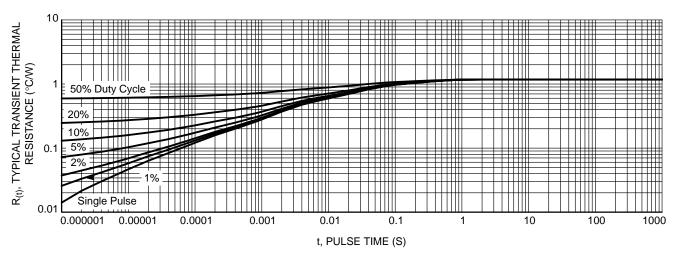
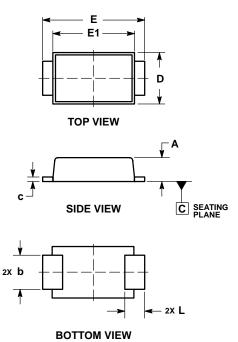


Figure 9. Typical Transient Thermal Response Characteristics, Junction-to-Case

PACKAGE DIMENSIONS

SMA-FL CASE 403AA ISSUE O

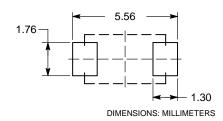


NOTES:

- DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M. 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.90	1.10	
b	1.25	1.65	
С	0.15	0.30	
D	2.40	2.80	
E	4.80	5.40	
E1	4.00	4.60	
L	0.70	1.10	

RECOMMENDED SOLDER FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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